## NSN 5961-01-236-3885

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-236-3885

Inclosure Material:
Ceramic all transistor and metal all transistor
Overall Length:
0.960 inches all transistor and 0.990 inches all transistor
Overall Height:
0.235 inches all transistor and 0.300 inches all transistor
Overall Width:
0.750 inches all transistor
End Application:
Radio set an/arc-143
Mounting Facility Quantity:
2 all transistor
Internal Configuration:
Junction contact all transistor
Internal Junction Configuration:
Npn all transistor
Component Function Relationship:
Matched
Component Name And Quantity:
5 transistor
Mounting Method:
Unthreaded hole all transistor
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
60.0 collector to emitter voltage, dc with base short-circuited to emitter all transistor and 50.0 collector to emitter reverse voltage all
transistor and 33.0 collector to emitter voltage/static/base open all transistor and 4.0 emitter to base voltage, static, collector open all
transistor
Current Rating Per Characteristic:
8.00 amperes source cutoff current all transistor
Power Rating Per Characteristic:
140.0 watts small-signal input power, common-collector absolute all transistor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction all transistor
Terminal Type And Quantity:
3 ribbon all transistor
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:

**Fiig:** A110a0

No